FOR ATTORNEYS' USE ONLY				
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	P69577US0			

ALL PATENTS, INCLUDING DESIGN				U.S.A. P69			ATTORNEYS' DOCKET NO.			
R APPLICATION BASED ON PCT; PARIS CONVENTION; N PRIORITY; OR PROVISIONAL APPLICATIONS			9577US0							
As a below named inventor, I declare that my residence, post office address and citizenship are stated below next to my name, the information given herein is true, that I believe that I am the program of the subject matter which is claimed and for which patent is sought on the invention entitled:  METHOD FOR FARMICATING SEMMICONDIVICTOR OPTICAL DEVICE.										
	MIE.	HOD F	OR FABRICA	TING SEMICON	DUCTOR OPT	ICAL DE	VICE	<del></del>		<del></del>
which is describ	ed and claimed in:	PCT Inte	emational Application	n No.		<del></del>	filed			
the attached	d specification	The sp	ecification in applicat	tion Serial No.			filed			
l acknowledge the duty to disclose information which is material to patentability as defined in Title 37, Code of Federal Regulations, §1.56.  Thereby claim foreign priority benefits under Title 35, United States Code, §119 (a)-(d) of any foreign application(s) for patent or inventor's certificate listed below and have also identified below										
Prior Foreign A	pplication(s)			-				Priority Cla	imed	
(Alumbar)	2003-85359		<del></del>	of Korea						
(Number)		(Cour	itry)		(Day/Month/Year Fil	ea)	1	Yes	No.	
(Number)		(Cour	ntry) .		(Day/Month/Year Fil	ed)		Yes	No	
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(Number)		Cour	ntry)		(Day/Month/Year Fil	ed)		Yes	No	
l hereby claim t	he benefit under Title 35, United	- 1 1	1	ted States provisional ap	plication(s) listed below	r.		1		
Application No.					<del></del>					
(A	oplication Serial No.)			(Filing Date)		(Status: r	natented per	ding ahang	foned)	
VER OF ATTO	RNEY: As a named invent	or, I hereby	appoint the follow	ving attorneys (Registr	ation No. ) to prosec	cute this appl	ication, rec		<u></u>	instructions
my agent, and N CLARKE HC	transact all business in the LMAN (22,769); MARVIN F	Patent and R. STERN (	Trademark Office 20.640): ALLEN S	e connected therewith.  S. MELSER (27,215): I	. HARVEY B. JACC MICHAEL R. SLOBA	BSON, JR. ( ASKY (26 42)	(20,851); 1): JONATI	•		
SEND CO	DRRESPONDENCE TO:	CUSTOME	R NO. 00136							
or (please use Attorney's Docket No.) (202) 638-6666  JACOBSON HOLMAN  PROFESSIONAL LIMITED LIABILITY COMPANY 400 SEVENTH STREET, N.W. WASHINGTON, D.C. 20004  (please use Attorney's Docket No.) (202) 638-6666  JACOBSON HOLMAN PROFESSIONAL LIMITED LIABILITY COMPANY										
		abbreviated	first or middle na				MIDDLE M	N N 4/5		
OF INVENTOR							MIDDLE IN			
RESIDENCE &				·			COUNTRY			IIP
CITIZENSHIP	Daejeon-Shi			Republic of Korea			Republic of Korea			
	CE POST OFFICE ADDRESS			CITY		STATI	ATE OR COUNTRY ZIP CC			IP CODE
	Eunhasu Apt. 104-207, Dunsan-Dong, Su-Gu			Daejeon-Shi			Republic of Korea 302-733			302-733
FULL NAME * OF INVENTOR	NVENTOR HAN			GIVEN NAME			MIDDLE NAME			
					Won		Seok			
RESIDENCE & CITIZENSHIP		on-Shi		——————————————————————————————————————						
POST OFFICE	· · · · · · · · · · · · · · · · · · ·			CITY	uone of Korea	STATE				
ADDRESS	Hanul Apt. 106-604, Sinsung-Dong, Yusong-Gu			Daejeon-Shi						305-777
	NTOR KIM			GIVEN NAME			MIDDLE NAME			
				Jong			Hee			
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				Daejeon-Shi					<del>- f</del>	
ADDRESS	T	• •	161	Dae	jeon-Shi	I	Republic o	f Korea		305-350
ADDRESS her declare that her that these signs section 1001	Kajong-Dong, Yusong- tall statements made herein tatements were made with to of Title 18 of the United Sta	Gu n of my owr he knowled	n knowledge are tr Ige that willful fals and that such willfi	l rue and that all statem e statements and the ul false statements ma	ents made on inform like so made are pur ay jeopardize the val	nation and be nishable by fi lidity of the a	elief are beli ne or impri oplication o	eved to be sonment or any pate	r both nt issu	and
ADDRESS her declare that her that these sign section 1001 NATURE OF IN	Kajong-Dong, Yusong- tall statements made herein tatements were made with to of Title 18 of the United Sta	Gu n of my owr he knowled	n knowledge are tr Ige that willful fals and that such willfi	ue and that all statem e statements and the ul false statements ma FINVENTOR 202*	ents made on inform like so made are pur ay jeopardize the val	nation and be nishable by fi	elief are beli ne or impri oplication o	eved to be sonment or any pate	r both nt issu	and
	APPLICATION B PRIORITY: OR B PRIORITY: OR B PRIORITY: OR B As a below nam original, first an hereto) of the si  which is descrit the attacher  if hereby state it is acknowledge is lacknowledge is lacknowledge in any foreign app Prior Foreign Application No. If hereby claim if any foreign app ((Number)  In hereby claim if in the state of the	APPLICATION BASED ON PCT: PARIS CONVEPRIORITY; OR PROVISIONAL APPLICATIONS  As a below named inventor, I declare that my noriginal, first and sole inventor (if only one nambereto) of the subject matter which is dalined a ME ME Miles of the subject matter which is dalined a ME ME Miles of the subject matter which is dalined a ME Miles of the subject matter which is dalined a ME ME Miles of the subject matter which is dalined a ME Miles of the subject matter which is dalined a ME Miles of the subject matter which is dalined a ME Miles of the subject matter which is dalined a ME Miles of the subject matter which is dalined a MIE Miles of the subject matter which is dalined at least one under the subject matter which is dalined at least one under the subject of the subject matter which is dalined at least one under the subject matter which is dalined at least one under the subject of the subject matter which is dalined at least one under the subject matter which is dalined at least one under the subject of the subject matter which is dalined at least one under the subject of the subject o	APPLICATION BASED ON PCT; PARIS CONVENTION: PRIORITY; OR PROVISIONAL APPLICATIONS  As a below named inventor, I declare that my residence, po- priginal, first and sole inventor (if only one name is listed at herelo) of the subject matter which is claimed and for which  METHOD F4  which is described and claimed in:  provided the attached specification    hereby state that I have reviewed and understand the cont   a chnowledge the duty to disclose information which is mat   hereby claim foreign priority benefits under Title 35, United   hereby graim foreign priority benefits under Title 35, United   hereby claim foreign priority benefits under Title 35, United   hereby claim the benefit under Title 35, United States Cod   not disclosed in the prior United States application in the ms   (Application No.    hereby claim the benefit under Title 35, United States Cod   not disclosed in the prior United States application in the ms   (Application Serial No.)    VER OF ATTORNEY: As a named inventor, I hereby   my agent, and transact all business in the Patent and   (Application Serial No.)    VER OF ATTORNEY: As a named inventor, I hereby   my agent, and transact all business in the Patent and   No. CLARKE HOLMAN (22,769); MARVIN R. STERN (   N. M. AISENBERG (19,007); WILLIAM E. PLAYER (3)    SEND CORRESPONDENCE TO: CUSTOME   SEND CORRESPONDENCE TO: CUSTOME   SEND CORRESPONDENCE TO: CUSTOME   Daejeon-Shi   POST OFFICE   POST OFFICE ADDRESS     Eunhasu Apt. 104-207, Dunsan-I   FULL NAME * FAMILY NAME     POST OFFICE   POST OFFICE ADDRESS     Hanul Apt. 106-604, Sinsung-Doi   TULL NAME * FAMILY NAME     POST OFFICE   POST OFFICE ADDRESS     Hanul Apt. 106-604, Sinsung-Doi   CESIDENCE & CITY     CITIZENSHIP   Daejeon-Shi   POST OFFICE   POST OFFICE ADDRESS     Hanul Apt. 106-604, Sinsung-Doi   CESIDENCE & CITY     CITIZENSHIP   Daejeon-Shi	APPLICATION BASED ON PCT: PARIS CONVENTION: PRIORITY: OR PROVISIONAL APPLICATIONS  As a below named inventor, I declare that my residence, post office address and priginal, first and sole inventor (if only one name is listed at 201 below), or an or hereio) of the subject matter which is claimed and for which patent is sought on hereio of the subject matter which is claimed and for which patent is sought on hereio) of the subject matter which is claimed and for which patent is sought on hereio) of the subject matter which is claimed and for which patent is sought on hereion of the subject matter which is claimed and for which patent is sought on hereion of the subject matter which is claimed and on which is material to patentability. I hereby claim foreign priority benefits under Title 35, United States Code, §119 any foreign application for patent or inventor's certificate having a filing date between the patent of patent or inventor's certificate having a filing date between the patent of patent or inventor's certificate having a filing date between the patent of patent or inventor's certificate having a filing date between the patent or inventor's certificate having a filing date between the patent or inventor's certificate having a filing date between the patent or inventor's certificate having a filing date between the patent or inventor's certificate having a filing date between the patent or inventor's certificate having a filing date between the patent or inventor's certificate having a filing date between the patent or inventor's certificate having a filing date between the patent or inventor's certificate having a filing date between the patent or inventor's certificate having a filing date between the patent or inventor's certificate having a filing date between the patent or inventor's certificate having a filing date between the patent or inventor's certificate having a filing date between the patent or inventor's certificate having a filing date between the patent or inventor's certificate having a	PATENTS, INCLUDING DESIGN APPLICATION BASED ON PCT; PARIS CONVENTION: APPLICATION BASED ON PCT; PARIS CONVENTION: PROVINTY: OR PROVISIONAL APPLICATIONS  As a below named inventor, I declare that my residence, post office address and cilizenship are stated by original, first and plaint inverse period of the subject matter which is dailared and for which patent is sought on the invention entitled:  METHOD FOR FABRICATING SEMICON  Which is described and calmed in:  PCT International Application No.  In the attached specification  The specification in application serial No.  If application in application serial No.  If application patentally as defined in Title 37, Co.  Interpolation of the subject matter which is described and dalmed in:  PCT International Application No.  If application in application of patent in the address of the above-identified specification, incl.  In the attached specification of the international application of the patent in the specification in application or patent and in a defined in Title 37, Co.  Interby state that I have reviewed and understand the contents of the above-identified specification, incl.  In the attached specification or inventor's certificate thaving a filting date before that of the application or patent or inventor's certificate thaving a filting date before that of the application or patent or inventor's certificate thaving a filting date before that of the application or patent or inventor's certificate thaving a filting date before that of the application or patent or inventor's certificate thaving a filting date before that of the application or patent or inventor's certificate thaving a filting date before that of the application or patent or inventor's certificate thaving a filting date before that of the application or patent or inventor's certificate thaving a filting date before that of the application or patent or pate	AND POWER OF ATTORNEY U.S.A.  APPLICATION BASED ON PROTECTIONS  As a babow named inventor, I declare that my residence, post office address and discensival part estated below next to my name, to remove the part of the subject matter which is darked and for which patient is sought on the invention antitled:  METHOD FOR FABRICATING SEMICONDUCTOR OPT  which is described and claimed in:  PCT International Application No.  The specification in application Serial No.  If applicable) and amended on  If applicable) and amended on  If applicable) and amended on  Interest y state that I have reviewed and understand the contents of the above-identified specification, including the claims, as an I have been described and observed and understand the contents of the above-identified specification, including the claims, as an I have been declared in the specification which is material to patentability as defined in Title 37, Code of Federal Regulated Prevention of the patient of mentions certificate interest to patentability as defined in Title 37, Code of Federal Regulated Prevention and Title 38, United States Code, \$11 (a)(1) of any foreign priority benefits under Title 38, United States Code, \$11 (a)(1) of any foreign application on which priority is set in the patient of the application on which priority is set in the patient of the patient of mentions certificate interest a large date before that of the application on which priority is set in the patient of the application on which priority is set in the patient of the application on which priority is set in the patient of the application on which priority is set in the patient of the application on which priority is set in the patient of the application on which priority is set in the patient of the application on which priority is set in the patient of the application on which priority is set in the patient of the application on which priority is set in the patient of the application on which priority is set in the patient of the application on which priority is set i	PATENTS INCLUDING DESIGN APPLICATION ABOD ON PET PARIS CONVENTION; PRIDERTY, OR PROVISIONAL APPLICATIONS  1. S a before name inverter, if deaths that my residence, post office address and estage that pure stated before next to my rame, but inverted original, first and side invertor (if only one name is listed at 201 below), or an original, first and side invertor of pure that the provision of the subject matter which is defined and for which patent is sough in the invention entities.  METHOD FOR FABRICATING SEMICONDUCTOR OPTICAL DE  Which is described and dealmed in:  PCT International Application No.  The specification in peptication No.  Private attached specification  The specification in application Serial No.  If application and the private international Application No.  International Private Priva	AND POWER OF ATTORNEY U.S.A.  PROSIDENT, OR PROVISIONAL APPLICATIONS  AND POWER OF ATTORNEY U.S.A.  PROVISIONAL APPLICATIONS  PROVISIONAL APPLICATIONS  AND POWER OF ATTORNEY U.S.A.  PROVISIONAL APPLICATIONS  AND POWER OF ATTORNEY U.S.A.  PROVISIONAL APPLICATIONS  METHOD FOR FABRICATIONS and an attained below and to my name, the information gripes herein criginal, first and sole inventor (if child you so name to listed at 201 below), or an original, first and joint inventor (if plural inventors are named below at 201-201 below). In a subject matter which is claimed and for which patient is soughed in the invention entities.  METHOD FOR FABRICATING SEMICONDUCTOR OPTICAL DEVICE  Price is described and distined in:  Provision is described in the distinct and in a provision is described in the distinct and in a provision is described in the distinct and in a provision is described in the distinct and in a provision is described in the distinct and in a provision is described in the provision in the provis	AND POWER OF ATTORNEY  PROCESSION APPLICATIONS  AND POWER OF ATTORNEY  U.S.A.  PROCESSION APPLICATIONS  AND POWER OF ATTORNEY  U.S.A.  PROCESSION OF REPORTSONAL APPLICATIONS  As a below name to reverse, a clear the name is billed at 201 below, a or original, first and point inventor (if plural inventor), a clear the name is billed at 201 below, a or original, first and point inventor (if plural inventor), a clear the name is billed at 201 below, a or original, first and point inventor (if plural inventor) are name to below at 201-203, or on add when the process or original, first and point inventor (if plural inventor) are name to below at 201-203, or on add when the process or original, first and point inventor (if plural inventors are named below at 201-203, or on add when the process or original, first and point inventor (if plural inventors are named below at 201-203, or on add when the process or original inventors (if plural inventors are named below at 201-203, or on add when the plural inventors are named below at 201-203, or on add when the plural inventors are named below at 201-203, or on add when the plural inventors are named below at 201-203, or on add when the plural inventors are named below at 201-203, or on add when the plural inventors are named below at 201-203, or on add when the plural inventors are named below at 201-203, or on add when the plural inventors are named below at 201-203, or on add when the plural inventors are named below at 201-203, or on add when the plural inventors are named below and 1 fiscal inventors are name	AND POWER OF ATTORNEY  PROCESSOR ASSOCIATIONS  AND POWER OF ATTORNEY  U.S.A.  PROCESSOR ASSOCIATION  PROCESSOR ASSOCIATION  PROCESSOR ASSOCIATION  METHOD FOR FABRICATING SEMICONDUCTOR OPTICAL DEV ICE  Thereby state that I have reviewed and understand the contracted of the above-fabricating semiconduction, including the claims, as arranded by any amendment referred to above.  I benefolding to the day to disclose information which is resterable patients and patients of the method optical patients and patients of the above fabrication in resterable patients and patients of the above fabricating semiconduction in the above fabricating semiconduction in the method optical patients and pa

204	FULL NAME *	FAMILY NAME	GIVEN NAME		MIDDLE NAME			
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	RESIDENCE &	CITY	STATE OR FOREIGN COUNTRY	STATE OR FOREIGN COUNTRY		COUNTRY OF CITIZENSHIP		
	CITIZENSHIP	Daejeon-Shi	Republic of Korea		Republic of Korea			
	POST OFFICE ADDRESS	POST OFFICE ADDRESS	CITY	STATE	OR COUNTRY	ZIP CODE		
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205	FULL NAME * OF INVENTOR	FAMILY NAME	GIVEN NAME	GIVEN NAME MIDDLE NAME				
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	CITIZENSHIP	Daejeon-Shi	Republic of Korea	l	Republic of Korea			
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H	FULL NAME * OF INVENTOR	FAMILY NAME	GIVEN NAME	MIDDLE NAME				
		PARK	Sang		Hee			
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206	CITIZENSHIP	Daejeon-Shi	Republic of Korea	Republic of Korea				
	ADDRESS	POST OFFICE ADDRESS	CITY	STATE	OR COUNTRY	ZIP CODE		
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		FAMILY NAME	GIVEN NAME		MIDDLE NAME			
	OF INVENTOR		•	ŀ				
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207	CITIZENSHIP			- 1				
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П		FAMILY NAME	GIVEN NAME	·	MIDDLE NAME	<u> </u>		
	OF INVENTOR							
208	RESIDENCE &	CITY	STATE OR FOREIGN COUNTRY		COUNTRY OF CITIZENSHIP			
	CITIZENSHIP							
		POST OFFICE ADDRESS	CITY	STATE	OR COUNTRY	ZIP CODE		
	ADDRESS	•	·					

Infurther declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and Further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment or both, 'Under section 1001 of Title 18 of the United States Code; and that such willful false statements may jeopardize the validity of the application or any patent issuing thereon.

SIGNATURE OF INVENTOR 204*	SIGNATURE OF INVENTOR 205*	SIGNATURE OF INVENTOR 206*			
young you gic	1 to Kym Kim	Shilep			
DATE February 18, 2004	DATE February 18, 2004	DATE February 18, 2004 (			
SIGNATURE OF INVENTOR 207*	SIGNATURE OF INVENTOR 208*	SIGNATURE OF INVENTOR 209*			
DATE	DATE	DATE			
Additional inventors are named on separately numbered sheets attached hereto.					

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